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Prediction of unexpected B_nP_n structures: promising materials for non-linear optical devices and photocatalytic activities†

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In the present work, a modern method of crystal structure prediction, namely USPEX conjugated with density functional theory (DFT) calculations, was used to predict the new stable structures of B_nP_n ($n = 12, 24$) clusters. Since $B_{12}N_{12}$ and $B_{24}N_{24}$ fullerenes have been synthesized experimentally, it motivated us to explore the structural prediction of $B_{12}P_{12}$ and $B_{24}P_{24}$ clusters. All new structures were predicted to be energetically favorable with negative binding energy in the range from -4.7 to -4.8 eV per atom, suggesting good experimental feasibility for the synthesis of these structures. Our search for the most stable structure of B_nP_n clusters led us to classify the predicted structures into two completely distinct structures such as α - B_nP_n and β - B_nP_n phases. In α - B_nP_n , each phosphorus atom is doped into a boron atom, whereas B atoms form a B_n unit. On the other hand, each boron atom in the β -phase was bonded to a phosphorus atom to make a fullerene-like cage structure. Besides, theoretical simulations determined that α - B_nP_n structures, especially α - $B_{24}P_{24}$, show superior oxidation resistance and also, both α - B_nP_n and β - B_nP_n exhibit better thermal stability; the upper limit temperature that structures can tolerate is 900 K. The electronic properties of new compounds illustrate a higher degree of absorption in the UV and visible-region with the absorption coefficient larger than 10^5 cm $^{-1}$, which suggests a wide range of opportunities for advanced optoelectronic applications. The β - B_nP_n phase has suitable band alignments in the visible-light excitation region, which will produce enhanced photocatalytic activities. On the other hand, α - B_nP_n structures with modest band gap exhibit large second hyperpolarizability, which are anticipated to have excellent potential as second-order non-linear optical (NLO) materials.

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1. Introduction

In the past decade, many attempts have been made to discover non-carbon fullerene-like structures based on their unique properties.^{1–9} The structural and electronic properties of clusters form an intermediate state between the individual atoms and crystals. Clusters have a remarkable impression in understanding the chemical bonding and the rational design of molecules with tailored physicochemical properties. In recent years, scientists have focused on studying boron-based materials because a significant number of unfamiliar structures of boron and its compounds have been explored.^{10–16} The electron configuration of boron is $2s^2 2p^1$; therefore, boron with one electron less than carbon has different characteristics compared to carbon, which can form fascinating and strong bonds with nearly all periodic table elements.^{16–18} On the other hand, phosphorus clusters with large pore sizes have received much attention in the past decade.¹⁸ Phosphorus is the diagonal

neighbor of carbon in the periodic table; therefore, the chemical bonding and structural chemistry of phosphorus are also interesting. Elemental phosphorus exists in different forms such as white, yellow, and black phosphorus but phosphorus is never found as a free element on earth because of its high reactivity.¹⁹

The group III-V compounds such as boron phosphide (BP) have been most generally investigated in their cubic crystal phase (c-BP).²⁰ Also, BP compounds can exist in planar (two-dimensional), tubular (one-dimensional), or spherical shapes (zero-dimensional), quite the same as graphene, carbon nanotubes, and fullerenes, respectively. All structures of BP compounds are prominent as large band-gap semiconductor materials having many advanced applications including microelectronics and optoelectronics,^{21,22} high thermal conductivity²³ hardness, chemical stability,^{23–25} and catalysis.^{20,26,27} Both boron and phosphorus elements can form 2D materials; it is interesting to determine whether the binary compound of boron and phosphorus can form stable clusters, which may display unusual structural and electronic properties better than both boron and phosphorus clusters.²⁸ Hence, it is desirable to consider the structures of boron phosphide clusters with different sizes.

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Numerous computational and experimental studies have considered the structural and electronic properties of group III–V compounds.^{18,19,29–32} In recent years, non-carbon (inorganic) $(XY)_n$ fullerenes of group III–V are of great scientific interest based on their promising candidates as optoelectronic devices^{33,34} and light-emitting diodes (LEDs).³⁵ $X_{12}Y_{12}$, $X_{16}Y_{16}$, $X_{24}Y_{24}$, and $X_{28}Y_{28}$ clusters, where X = group III atom and Y = group V atom, are predominant inorganic $(XY)_n$ fullerenes.⁸ Computational investigations on $(XY)_n$ fullerenes have demonstrated that $(XY)_{12}$ has the highest thermodynamic stability, which is known as a magic cluster.^{36–38} In this regard, Strout *et al.* ascertained that the $X_{12}Y_{12}$ nano-cages are the most stable structures between all fullerene-like $(XY)_n$ (X = B, Al, Ga, ... and Y = N, P, As, ...) structures.³⁶ $B_{12}N_{12}$ and $B_{24}N_{24}$ fullerene-like clusters were synthesized by Oku *et al.*^{39–41} and detected using time-of-flight mass spectrometry. The $B_{12}N_{12}$ cluster is shown as the most stable structure among $B_{12}N_{12}$, $B_{16}N_{16}$, and $B_{28}N_{28}$.⁴² Other $(XY)_{12}$ clusters such as $Al_{12}N_{12}$, $Al_{12}P_{12}$, $B_{12}N_{12}$, and $B_{12}P_{12}$ are of much interest owing to their unique chemical and physical properties. In this regard, many theoretical studies had been focused on ascertaining the relative stabilities of different sizes of these nano-cages.^{18,19,30–32,38,43}

Boron phosphide $(BP)_n$ clusters are an attractive member of the X_nY_n nano-cage family with unique physical and electrochemical properties. Since $B_{12}N_{12}$ and $B_{24}N_{24}$ fullerenes have been synthesized experimentally,^{39–41} it has motivated researchers to investigate the structural and electronic properties of $B_{12}P_{12}$ and $B_{24}P_{24}$ fullerene-like clusters. In all the previous studies, $X_{12}Y_{12}$ and $X_{24}Y_{24}$ clusters have been considered as fullerene-like structures, which consist of four-, six-, and eight-membered rings, and have large HOMO–LUMO gaps, almost zero dipole moment, and nearly zero hyperpolarizability.³¹ It should be mentioned that in all the previous studies, $(XY)_n$ clusters (X = B, Al, Ga, and Y = P, As) were made directly by replacing B and N atoms of the already known structures of the $(BN)_n$ cages with other atoms, then the bonding length and angle are adjusted by further calculations. Based on this strategy, the main questions are that whether this method is correct and whether this method give the lowest energy structure. We believe that structural prediction can answer these questions. Structural prediction based on first-principles calculation has served as a very useful tool in materials research. Exploring 0, 1, and 2-dimensional (0, 1, 2-D) materials from molecular design and global search have been a hot-topic. Based on our knowledge, no study has been conducted to predict the structure of boron phosphide $(BP)_n$ clusters. Also, all previous studies on these materials have been based on the structure of boron nitride $(BN)_n$ clusters. The structure of B_nP_n in all previous investigations by other researchers has been reported to be cage-shaped, which is exactly similar to the $(BN)_n$ clusters, in which the P atoms are replaced by N atoms. It motivated us to use an evolutionary algorithm to predict the structures of boron phosphide clusters. For the first time, we used the evolutionary algorithm as implemented in the USPEX code to search the ground state structure of the B_nP_n clusters, including $B_{12}P_{12}$ and $B_{24}P_{24}$ clusters. It should be noted that the $B_{12}N_{12}$ and $B_{24}N_{24}$

fullerenes have been synthesized experimentally; hence, the $B_{12}P_{12}$ and $B_{24}P_{24}$ structures were chosen.

2. Computational details

We used the evolutionary algorithm as executed in the USPEX code to search for the potential energy surface of the $B_{12}P_{12}$ and $B_{24}P_{24}$ clusters. USPEX code by evolutionary algorithm solves the central problem of crystal structure prediction of theoretical crystal chemistry.^{44–47} An adequate number of initial structures, more than 1800 configurations in 50 generations by the USPEX method, was used to ensure that the global minimum is attained. The geometrical relaxation, stability assessment, and optoelectronic properties of the predicted B_nP_n clusters were carried out by the Vienna *ab initio* simulation package (VASP).^{48,49} The generalized gradient approximation (GGA) scheme, developed by Perdew–Burke–Ernzerhof (PBE) and projector-augmented wave (PAW)⁵⁰ potentials were used. The dispersion-corrected DFT-D3 method with Becke-Jansoon damping was used in all the structure optimizations to account for the weak van der Waals interactions.^{51,52} The low-lying energy isomers, whose relative energies are in the range of 0–2.5 eV with respect to the most stable structure, were carefully re-optimized to distinguish the correct global minimum structure of each B_nP_n cluster. The screen hybrid HSE06 method⁵³ with the mixing parameter alpha value of 0.25 was carried out to consider the electronic properties and optical absorption of the predicted clusters. An energy cutoff of 400 eV was used for the plane-wave expansion. All geometries were relaxed until the convergence criteria of energy (10^{-6} eV) and force on each atom (0.02 eV \AA^{-1}) were satisfied. It should be pointed out that the structures were located in the middle of a box with a vacuum spacing of ~ 10 \AA in all the directions to neglect the interactions between the adjacent cells. To further examine the thermal stability proposed for the B_nP_n clusters, *ab initio* molecular dynamics (AIMD) simulations using the canonical (NVT) ensemble were performed. The simulations are accomplished using a Nosé–Hoover thermostat at finite 300, 600, and 900 K temperatures for 5000 fs with a time step of 1.0 fs.

3. Results and discussion

3.1. Geometry and stability

Based on the USPEX method conjugated with spin-polarized first-principles calculations, a comprehensive study to explore their ground state structures of B_nP_n (n = 12, 24) and low-lying isomers of these clusters was performed employing the evolutionary algorithm. The USPEX method has been successful used before to explore a wide range of materials.^{54–56} Among the structure search by evolutionary algorithm, more than 1800 different structures for each cluster were predicted. We mainly focused on the low-lying isomers in the energy range of 0–2.5 eV with respect to the most stable structure. We re-optimized these structures to get the precise total energy and the atomic structures. The lowest-energy structures and low-lying energy isomers of the B_nP_n (n = 12, 24) clusters are displayed in Fig. 1 and 2.



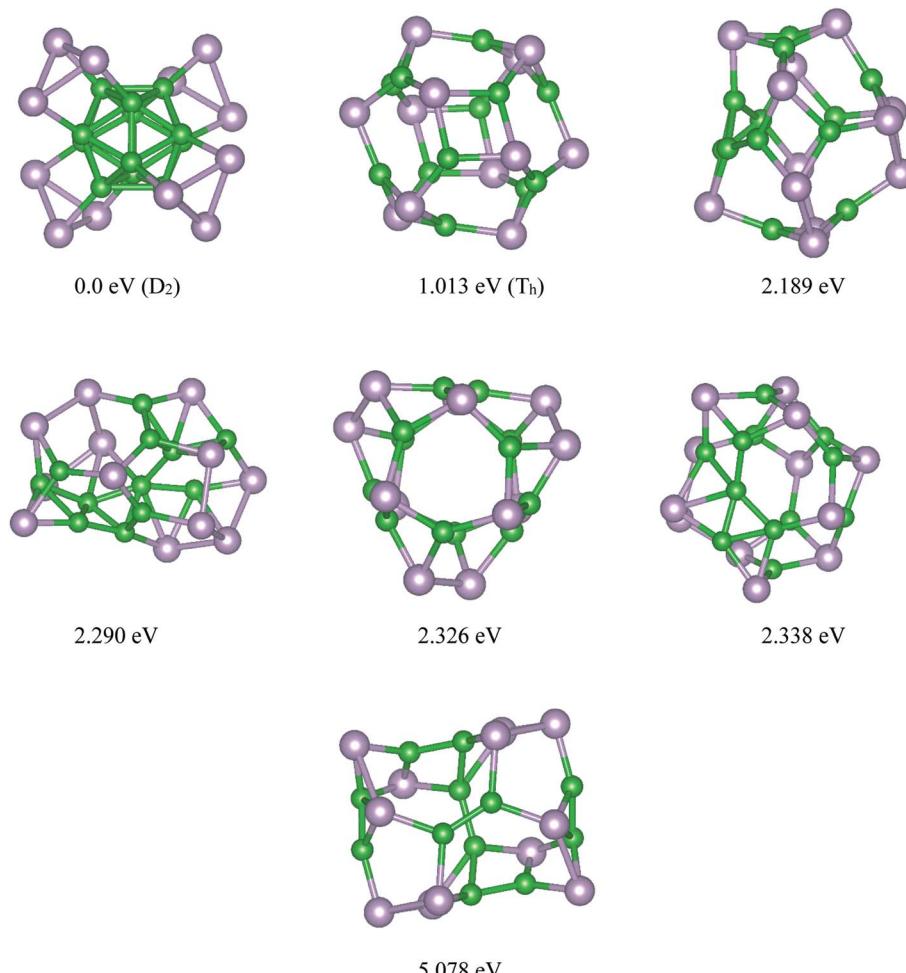


Fig. 1 Lowest-energy structures and low-lying energy isomers of the $P_{12}B_{12}$ clusters. The green and gray balls represent the B and P atoms, respectively.

Our search for the most stable structure of B_nP_n clusters led us to classify the predicted structures into two completely distinct structures. Interestingly, it can be classified into two α - and β -phases. In the α -phases, each phosphorus atom is doped into a boron atom while the B atoms form a B_n unit. This type of predicted structure named α - B_nP_n structure, is reported for the first time. On the other hand, in the β -phase, each boron atom is bonded to each phosphorus atom to make a cage cluster, which is named the β - B_nP_n structure. The final relaxed geometry of the α - B_nP_n and β - B_nP_n systems with their symmetries, their low-lying energy isomers, and relative stabilities are displayed in Fig. 1 and 2. To assist comprehension, two different views of the ground-state structures, as well as the first low-lying energy isomers of α - B_nP_n and β - B_nP_n are shown in Fig. S1 and S2,[†] respectively.

Based on our global structure search, the most stable structure of the $B_{12}P_{12}$ cluster with D_2 symmetry is alpha rhombohedral-shaped, named as α - $B_{12}P_{12}$. In this structure, the arrangement of 12 boron atoms in the alpha-tetragonal boron structure made a B_{12} building block, while each phosphorus atom bonded to each boron atom of the alpha tetragonal B_{12}

unit. To date, this is the first time that this type of structure has been reported for the $B_{12}P_{12}$ structure. In this beautifully predicted structure, each P atom is covalently bonded to each boron atom of the B_{12} unit with an average B-P bond length of ~ 1.98 Å. In other words, the surface of the B_{12} unit is covered with phosphorus atoms. The average B-B bond lengths in the B_{12} unit of α - $B_{12}P_{12}$ (~ 1.77 Å) is nearly the same as that of the average B-B bond in the B_{12} icosahedron (1.75 Å).⁵⁷ As seen in Fig. 1, each phosphorus atom is covalently bonded to two neighboring phosphorus atoms to make a three-membered ring, in which the phosphorus atoms are lying in a plane. It can be imagined that the triangular rings of phosphorus have grown on the B_{12} unit, while each of these P atoms are bonded to each of the B atoms. In this situation, the hybridization of each P atom is sp^3 . The calculated average P-P bond length and the P-P-P bond angles of α - $B_{12}P_{12}$ are about 2.36 Å and 60°, respectively, which is comparable to the P-P bond length (2.23 Å) in phosphorene.⁵⁸ The experimental evidence for our predicted α - $B_{12}P_{12}$ structure is the alpha tetragonal allotrope of boron determined in 1951 by Hoard *et al.*⁵⁹ The same as α - $B_{12}P_{12}$ structure, this structure is made up of just one building block of



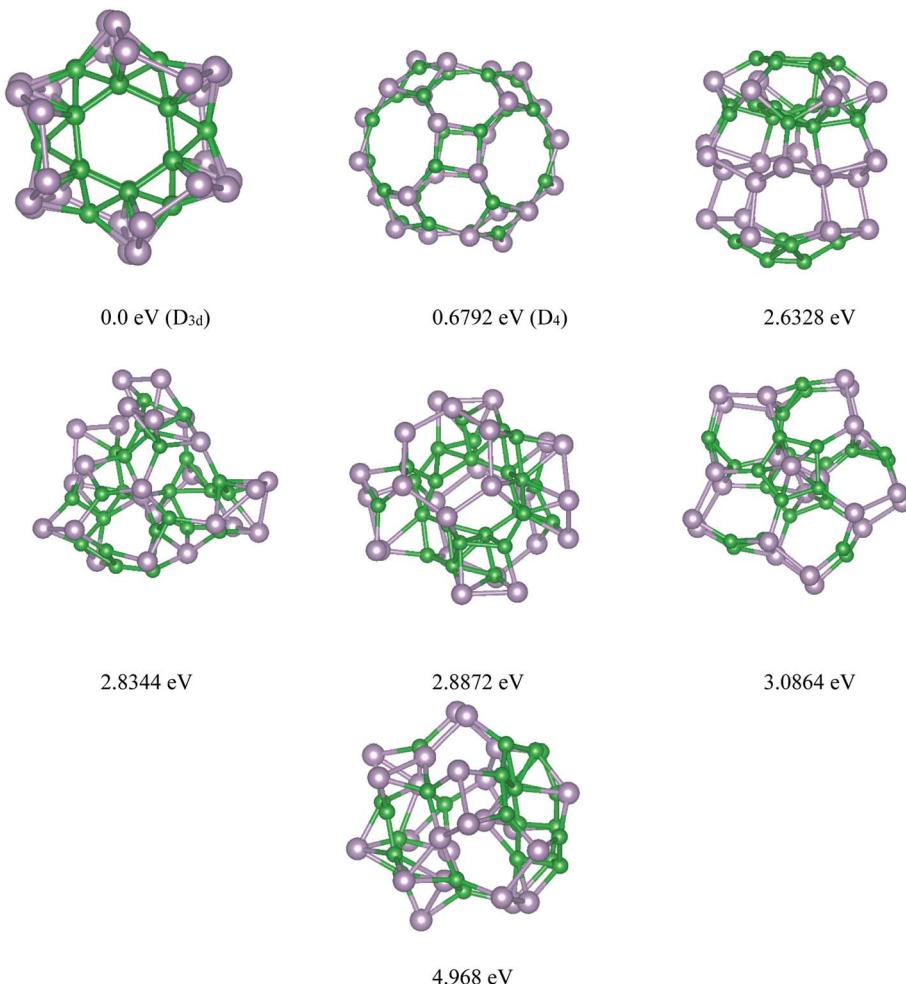


Fig. 2 Lowest-energy structures and low-lying energy isomers of the $P_{24}B_{24}$ clusters. The green and gray balls represent the B and P atoms, respectively.

the alpha-tetragonal B_{12} boron structure. Another evidence for the new predicted structure is $B_{13}P_2$.⁶⁰ The crystal structure of $B_{13}P_2$ shows that this is an alpha rhombohedral boron structure with two P atoms in the unit cell. Interestingly, $B_{13}P_2$ was made up of just one B_{13} building block, in which P atoms connected each building block.⁶⁰

The first low-lying energy structure of $B_{12}P_{12}$ is fullerene-like with a large cavity. This type of structure was named as the β - $B_{12}P_{12}$ structure. The structure of β - $B_{12}P_{12}$ is a polyhedral boron-phosphide structure composed of four tetragons and hexagons. As seen in Fig. 1, the stability of the low-lying energy β - $B_{12}P_{12}$ structure is less than the α - $B_{12}P_{12}$ configuration with a large amount of energy of about 1.013 eV. Based on our calculations, it has an average diameter of 0.586 nm, while the C_{60} fullerene has an average diameter of ~ 0.7 nm.^{61,62} Due to the large cavity of β - $B_{12}P_{12}$, the same as that of C_{60} fullerene, it can be suitable for various applications such as gas storage, encapsulation of atoms, or molecules inside its cage, and endohedral metallofullerenes. As we know, the endohedral metallofullerenes have attracted much attention due to their unique potential applications such as superconductors and non-linear optical

(NLO) devices. The relaxed geometry of the β - $B_{12}P_{12}$ cluster indicated that only B-P bonds with an average bond length of ~ 1.911 Å were found in this nano-cage. It should be noted that two types of B-P bonds were found in this structure; the first is the B-P bond in the hexagonal ring, which is named **I**(B-P), and the second is the B-P bond in the tetragonal rings, which is named **II**(B-P). These results are collected in Table 1 and are shown in Fig. S1.[†]

Table 1 The PBE-D3 structural parameters of the relaxed geometries of the most stable structures and the first low-lying energy isomers of the $(PB)_n$ clusters (atom numbering is in accordance with see ESI Fig. S1 and S2)

Type	B-P (Å)			B-B (Å)		
	I(B-P) _h	II(B-P) _T	III(B-P) _O	P-P (Å)	I(B-B) _h	II(B-B) _T
α - $B_{12}P_{12}$	1.98	—	—	2.36	1.77	—
β - $B_{12}P_{12}$	1.900	1.922	—	—	—	—
α - $B_{24}P_{24}$	1.972	2.012	—	2.231	1.746	1.788
β - $B_{24}P_{24}$	1.918	1.905	1.871	—	—	—



The final relaxed geometry of the ground-state structure and the low-lying isomers of the $B_{24}P_{24}$ cluster, together with their symmetries and relative stabilities, are shown in Fig. 2 and S2.† By looking at the predicted structures of $B_{24}P_{24}$, it was found that the ground state structure of $B_{24}P_{24}$ is α - $B_{24}P_{24}$ with a high symmetry of D_{3d} , in which all the boron atoms are arranged as B_{24} unit, while the phosphorus atoms cover the B_{24} surface. It should be pointed out that the B_{24} motif in α - $B_{24}P_{24}$ is composed of two hexagons on the bottom and the top, six hexagons surrounding the waist, and 12 trigons alternatively connected to each hexagon. To date, this has been the first time that this type of structure has been reported for the $P_{24}B_{24}$ cluster. In this unique predicted structure, each P atom is bonded to one or more boron atoms of the B_{24} motif as the surface of the B_{24} unit is covered with phosphorus atoms. The average B–P bond length is obtained as ~ 1.99 Å, which is comparable with the B–P bonds in phosphinoboranes and related compounds.⁶³ In detail, two types of B–P bonds such as types I and II can be found in the α - $B_{24}P_{24}$ structure (Fig. S2†), and the corresponding values of these bond lengths are collected in Table 1. On the other hand, the calculated values of the P–P and B–B bond lengths are summarized in Table 1. The average P–P bond length is obtained as 2.231 Å while for the B–B bonds, we found two different types of B–B in τ ηε α - $B_{24}P_{24}$ structure. I (B–B)_h represents the bonded B atoms to each other in hexagons (1.746 Å) and II (B–B)_T shows the bond length between the boron atoms in trigonal geometry with a bond length of about 1.788 Å. These results are comparable with the average B–B bond in the B_{12} icosahedra (1.75 Å).⁵⁷ For simplicity of visualization, two different views of the B_{24} unit without P atoms are shown in Fig. S3.† This result is contradictory to that reported for pristine B_{24} clusters, where the quasi-planar and rather irregular polyhedrons are prevalent.⁶⁴ It should be reminded that the ionic quasi-planar B_{24} structure has been experimentally synthesized.⁶⁴ The evidence for our predicted α - $B_{24}P_{24}$ cluster is the encapsulation of a transition metal in the fullerene-like boron cages.^{65–67} Yanming Ma and coworkers⁶⁵ predicted transition metal-doped B_{24} clusters using first-principles swarm-intelligence-based structure searches. They found that the low-lying energy structures were generally a cage-like structure. It can be concluded that doping is a significant factor in determining the geometry of boron-based materials.

Fig. 2 represents the selected low-lying energy $B_{24}P_{24}$ structures with their symmetry and energy relative to the ground-state D_{3d} α - $B_{24}P_{24}$ structure. The first low-lying energy structure belongs to the β - $B_{24}P_{24}$ fullerene-like structure. As seen from this figure, the β - $B_{24}P_{24}$ structure with D_4 symmetry is less stable than the ground-state α - $B_{24}P_{24}$ structure by a large amount of energy (~ 0.68 eV). It should be reminded that the fullerene-like structure is proposed as the ground-state structure of the $X_{24}Y_{24}$ clusters. The investigated structures of $X_{24}Y_{24}$ in all the previous studies^{19,30–34,38,43} are based on the strategy in which B and N atoms are directly replaced with X and Y atoms in the already known structures of the $(BN)_n$ nano-cages, and then the bonding length and angle are adjusted for further calculation. In the case of B_nP_n , our global search indicated that the B_nP_n fullerene-like structure is a low-lying isomer. The β -

$B_{24}P_{24}$ fullerene-like structure with a 0.859 nm cavity, which is larger than the C_{60} cavity (0.7 nm), includes 12 tetragonal, eight hexagonal, and six octagonal BP rings. Table 1 summarizes different boron–phosphorus (B–P) bond lengths of the most stable structures and the first low-lying energy structures of $B_{24}P_{24}$. As can be seen in Fig. 2 and Table 1, two kinds of B–P bonds are recognized for the β - $B_{24}P_{24}$ structures with B–P bonds between tetragonal/hexagonal rings, named type I (B–P), with an average bond length of about 1.918 Å, B–P bonds between tetragonal/octagonal rings, named as type II (B–P) (~ 1.905 Å), and the B–P bonds between hexagonal/octagonal ring, named type III, with bond length of about 1.871 Å.

The energy difference between the most stable structure and other competing structural isomers of each compound are essential to figure out the possibility of their synthesis under different experimental conditions. The energy difference between the lowest energy structure of α - $B_{12}P_{12}$ / α - $B_{24}P_{24}$ and the first low-lying energy β - $B_{12}P_{12}$ / β - $B_{24}P_{24}$ structures is 0.059/0.061 eV per atom, respectively, implying that the α - B_nP_n structures are more stable than the β - B_nP_n structures (≥ 5.7 kJ mol⁻¹). Based on our predictions, β - $B_{12}P_{12}$ and β - $B_{24}P_{24}$ clusters may not coexist with the α - B_nP_n structures at room temperature when compared with the thermal energy at 300 K (0.026 eV). Hence, it can be concluded that the B_nP_n fullerene-like structures can exist at higher temperatures (> 300 K). In the case of other low-lying energy isomers of $B_{12}P_{12}$ and $B_{24}P_{24}$ structures, the second and third metastable structures are less stable than the global minimum α - $B_{12}P_{12}$ and α - $B_{24}P_{24}$ structures by a large amount of energy (> 2.2 eV).

Now, we return to investigate the thermodynamic stability of the α - B_nP_n and β - B_nP_n clusters, which need to certify their stability and facility experimental synthesis. To estimate the thermodynamic stability of the predicted clusters, the binding energy per atom (E_b , eV per atom) is calculated. The relative binding energy (E_b) is an effective parameter to show the thermodynamic stability of the clusters and it is defined as below.

$$E_{\text{bin}} = [E_{(\text{BP})n} - n/2(E_B + E_P)]/n \quad (1)$$

where $E_{(\text{BP})n}$ and E_B/E_P illustrate the total energies of the B_nP_n clusters and a single boron/phosphorus atom, respectively.

As seen in Table 2, the calculated binding energies of the α - B_nP_n and β - B_nP_n structures are in the range from -4.723 to -4.803 eV per atom, which is much better or comparable to that of other 2D materials such as phosphorene,⁶⁸ carbon phosphide,⁶⁹ Al_2C sheet,⁷⁰ and silicene,⁷¹ having 3.48, 5.32, 3.94, and 3.55 eV per atom, respectively, indicating the very good stability of these materials. Furthermore, the binding energy of the predicted clusters was compared with that of different 2D-BP allotropes. The calculated binding energies for the α - B_nP_n and β - B_nP_n structures is comparable with the binding energy of 2D α_0 -BP (4.91 eV per atom), α_1 -BP (4.82 eV per atom), β_0 -BP (4.72 eV per atom), β_1 -BP (4.54 eV per atom), and γ -BP (4.44 eV per atom).⁷² Moreover, the binding energies for these new configurations are even close to the already synthesized B_{40} ,⁷³ $\text{M}@\text{B}_n$,⁶⁶ and B_{24} clusters.⁶⁴ Hence, it can be concluded that the α - B_nP_n and β - B_nP_n structures have excellent stability and

Table 2 Symmetries, calculated binding energy per atom (E_{bin} , eV per atom), HOMO–LUMO energy gaps (Δ_g , eV), and VBM and CBM (eV) of the $(\text{BP})_n$ clusters. The structural and energetic properties are calculated using the PBE-D3 method, while the HSE06 functional was used to calculate the electronic properties (Δ_g , VBM, CBM, and summation Bader partial charge on all B and P atoms (esu) of the HSE06 functional based on the PBE-D3 relaxed structures

Type	$\alpha\text{-B}_{12}\text{P}_{12}$	$\beta\text{-B}_{12}\text{P}_{12}$	$\alpha\text{-B}_{24}\text{P}_{24}$	$\beta\text{-B}_{24}\text{P}_{24}$
HOMO (eV)	−5.563	−6.186	−4.315	−5.572
LUMO (eV)	−4.895	−2.977	−3.691	−2.592
VBM (eV)	−6.120	−6.787	−5.313	−6.311
CBM (eV)	−5.532	−3.579	−4.689	−3.331
E_g (eV)	0.668	3.208	0.624	2.98
E_b (eV per atom)	−4.782	−4.723	−4.803	−4.742
Total partial charge (esu) on all B and P atoms				
B	0.577	3.555	2.313	8.242
P	−0.577	−3.555	−2.313	−8.242

possible experimental synthesis. As seen in Table 2, the $\alpha\text{-B}_n\text{P}_n$ structures are more stable than the corresponding $\beta\text{-B}_n\text{P}_n$ structure and the maximum binding energy of −4.803 eV per atom belongs to the $\alpha\text{-B}_{24}\text{P}_{24}$ structure.

3.2. Dynamic and chemical stability

Next, the dynamic stability of the predicted clusters was also investigated. The vibrational frequencies at the gamma points for the most stable structures as well as the first low-lying isomers were calculated. Based on these calculations, no negative vibration frequency could be found, confirming that the most stable and the first low-lying structures are dynamically stable. Furthermore, the thermal stability of the most stable structure and the first low-lying energy isomers of the studied B_nP_n clusters was performed using *ab initio* molecular dynamic simulations (AIMD) at three different (300, 600, and 900 K) temperatures by the NVT-ensemble with the Nosé–Hoover thermostat. As represented in Fig. 3 and 4, the predicted structures equilibrated at 300 K from the AIMD simulations. Furthermore, there is no broken bond and the initial clusters are well maintained during the AIMD simulation for 5 ps with a time-step of 1 fs. As shown in these figures, the total potential energy only fluctuates around a certain constant magnitude, which indicates the most stable structures of the B_nP_n clusters and the first low-lying isomers are thermodynamically stable and could hold their structural integrity at room temperature. It can be seen from Fig. 3 and 4 that after heating both $\alpha\text{-B}_n\text{P}_n$ and $\beta\text{-B}_n\text{P}_n$ structures, the basic structure of the clusters is also well maintained at 600 and 900 K. Furthermore, the thermal stability of the $\alpha\text{-B}_{24}\text{P}_{24}$ cluster at a higher temperature such as 1200 K was also examined (Fig. S4†). Based on the AIMD simulations, when the temperature reaches as high as 900 K, the bond elongation of the 6-membered ring occurs. It can be anticipated that as the temperature increases, bond stretching is also increased. Hence, the upper limit of temperature that the structures can tolerate is 900 K and the bond stretching occurs between 900 and 1200 K.

Chemical stability in air and other environments is an important issue that may limit the future applications of materials. Furthermore, a major problem with atoms located on the surface of the materials is their reaction with oxygen, nitrogen, and water in air; hence, the surface chemistry of these materials is essential in determining the intrinsic properties.^{74,75} Some phosphorus-based materials such as 2D-phosphorene and black phosphorus are known to oxidize and break down in ambient conditions because of the lone atomic pairs of the P atoms at the surface.^{76–80} Generally, P atoms favor the formation of the trigonal pyramidal sp^3 bonded configuration.⁸¹ It is found that in the $\alpha\text{-B}_{12}\text{P}_{12}$ cluster, each P atom with sp^3 hybridization bonding with two P and one B neighbor atoms has one lone pair of electrons; hence, it motivates us to investigate the effects of oxygen, nitrogen, and water–gas molecules on the stability of the $\alpha\text{-B}_n\text{P}_n$ structures.

The AIMD simulation was used to investigate the interaction between $\alpha\text{-B}_n\text{P}_n$ and gaseous phase O_2 , N_2 , and H_2O molecules at room temperature. As an initial model, randomly, eight O_2 , N_2 , and H_2O molecules were added around the $\alpha\text{-B}_{12}\text{P}_{12}$ and $\alpha\text{-B}_{24}\text{P}_{24}$ clusters with $1 \times 1 \times 1$ unit cells at an initial distance of 3.5–4 Å from the cluster surface (see Fig. 5 and 6). The lattice parameters of the optimized $\alpha\text{-B}_n\text{P}_n$ structures at the PBE + D3 level are $a = 19.4$ Å, $b = 19.4$ Å, and $c = 19.4$ Å. The AIMD simulations were performed for 7 ps with a time step of 1.0 fs under 300 K. Based on our AIMD simulations, it can be seen that generally the $\alpha\text{-B}_n\text{P}_n$ clusters have relatively high stability in the presence of O_2 , N_2 , and H_2O molecules. Obviously, after 7 ps of contact, some O_2 molecules dissociated into O atoms and chemisorbed onto the $\alpha\text{-B}_{12}\text{P}_{12}$ surface. The P–O bonds with a bond length of about 1.524 Å are short and could be polar due to the difference in the electronegativity between the P and O atoms. Apart from the negative outcomes due to the $\alpha\text{-B}_{12}\text{P}_{12}$ interaction with the O_2 molecule, controlled passivation might lead to new stable structures for gas sensing. It should be reminded that the basic structure of the $\alpha\text{-B}_{12}\text{P}_{12}$ cluster is also well maintained after 7 ps of contact. In contrast, the phenomena of O_2 dissociation has not been found on the $\alpha\text{-B}_{24}\text{P}_{24}$ surface in the AIMD simulation (see Fig. 6), which indicated the high oxidation resistance of the $\alpha\text{-B}_{24}\text{P}_{24}$ structure. This result is very exciting and is different from the result we expected. Furthermore, the simulations identify that no interaction is observed between the $\alpha\text{-B}_{12}\text{P}_{12}$ / $\alpha\text{-B}_{24}\text{P}_{24}$ structures with N_2 and H_2O molecules, which indicates the high stability of this type of structure. To confirm the chemical stability of the $\alpha\text{-B}_n\text{P}_n$ clusters, the adsorption of O_2 , N_2 , and H_2O gas molecules onto the $\alpha\text{-B}_n\text{P}_n$ surfaces was performed. The adsorption energy (E_{ads} , eV per gas molecule) can be calculated as follows.

$$E_{\text{ads}} = (E_{\text{cluster-gas}} - (E_{\text{cluster}} + nE_{\text{gas}})/n$$

where n is the number of gas molecules per unit cell. The $E_{\text{cluster-gas}}$ term stands for the total energy of the $\alpha\text{-B}_n\text{P}_n$ clusters after gas adsorption. The E_{cluster} and E_{gas} terms are the total energies of the isolated $\alpha\text{-B}_n\text{P}_n$ cluster and the gas molecule, respectively. According to the above expression, the negative E_{ads} exhibits that complex formation is thermodynamically

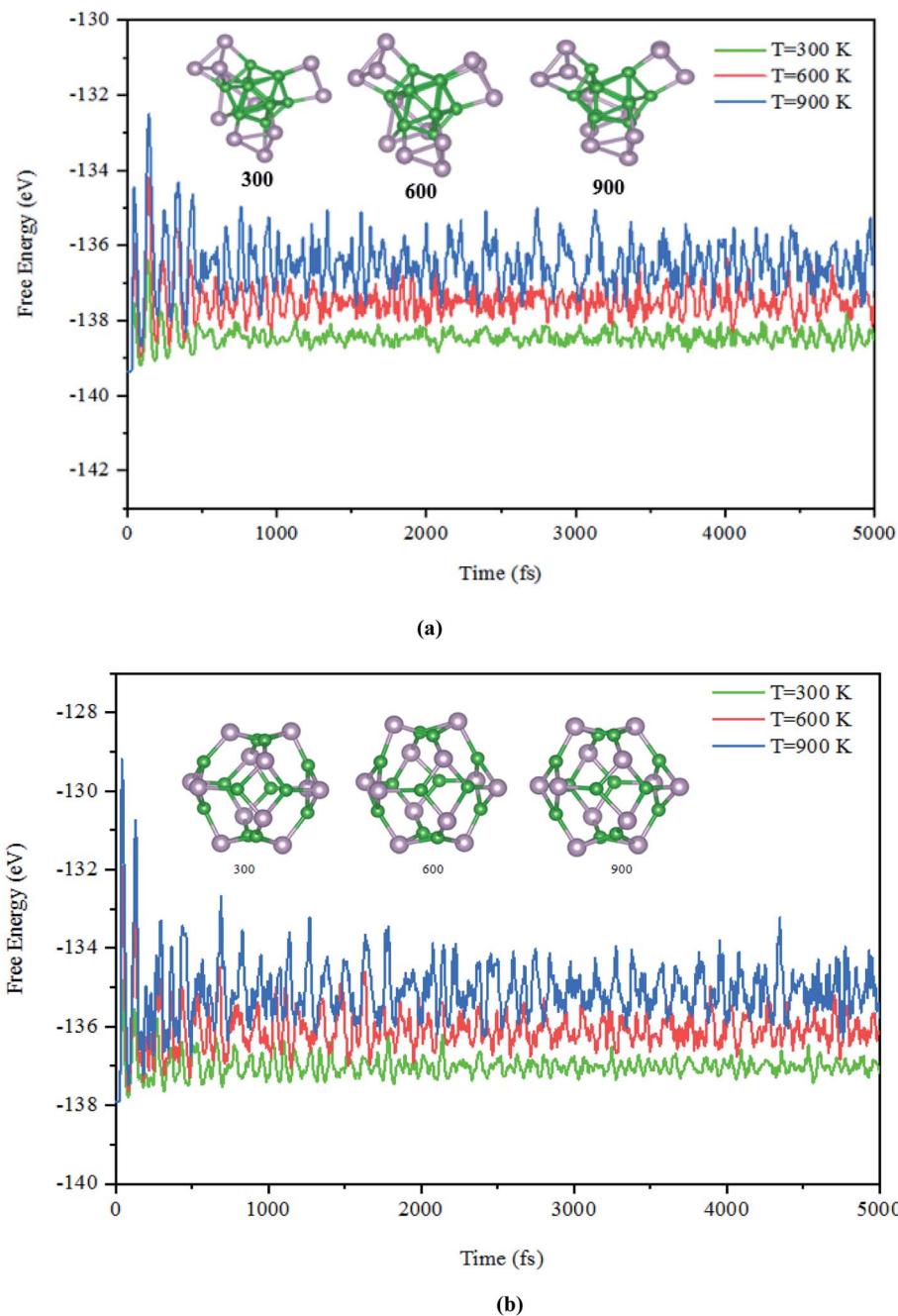


Fig. 3 The snapshots of the most stable structures for a time of 5 ps of (a) α -B₁₂P₁₂ and (b) β -B₁₂P₁₂. The temperature of the AIMD was set to 300, 600, and 900 K.

favorable. The calculated adsorption energy of the studied complexes is plotted in Fig. S5.† As seen from this figure, the adsorption energy of the O₂ molecules onto the α -B₁₂P₁₂ surface is favorable ($-42.93\text{ kJ mol}^{-1}$ per O₂ molecule). According to the adsorption energy values, it is found that O₂ physisorbs over α -B₁₂P₁₂ with an adsorption energy of about -43 kJ mol^{-1} . These results are in good accordance with the results of the AIMD simulation, which were used to investigate the chemical stability α -B_nP_n and O₂, N₂, and H₂O gas molecules. Hence, it can be concluded that the structural integrity of α -B_nP_n can be

retained perfectly in the environment of gaseous phase O₂, N₂, and H₂O at room temperature.

3.3. Electronic and optical properties

Based on the relaxed geometries, the electronic properties of the most stable structure, along with the first low-lying isomer of the B_nP_n structures, were also investigated. The HOMO-LUMO (H-L) energy gap (E_{gap}) is a fruitful parameter for examining the kinetic stability in molecules. The E_{gap} is the energy needed to excite the electron from the HOMO to the LUMO, where a large

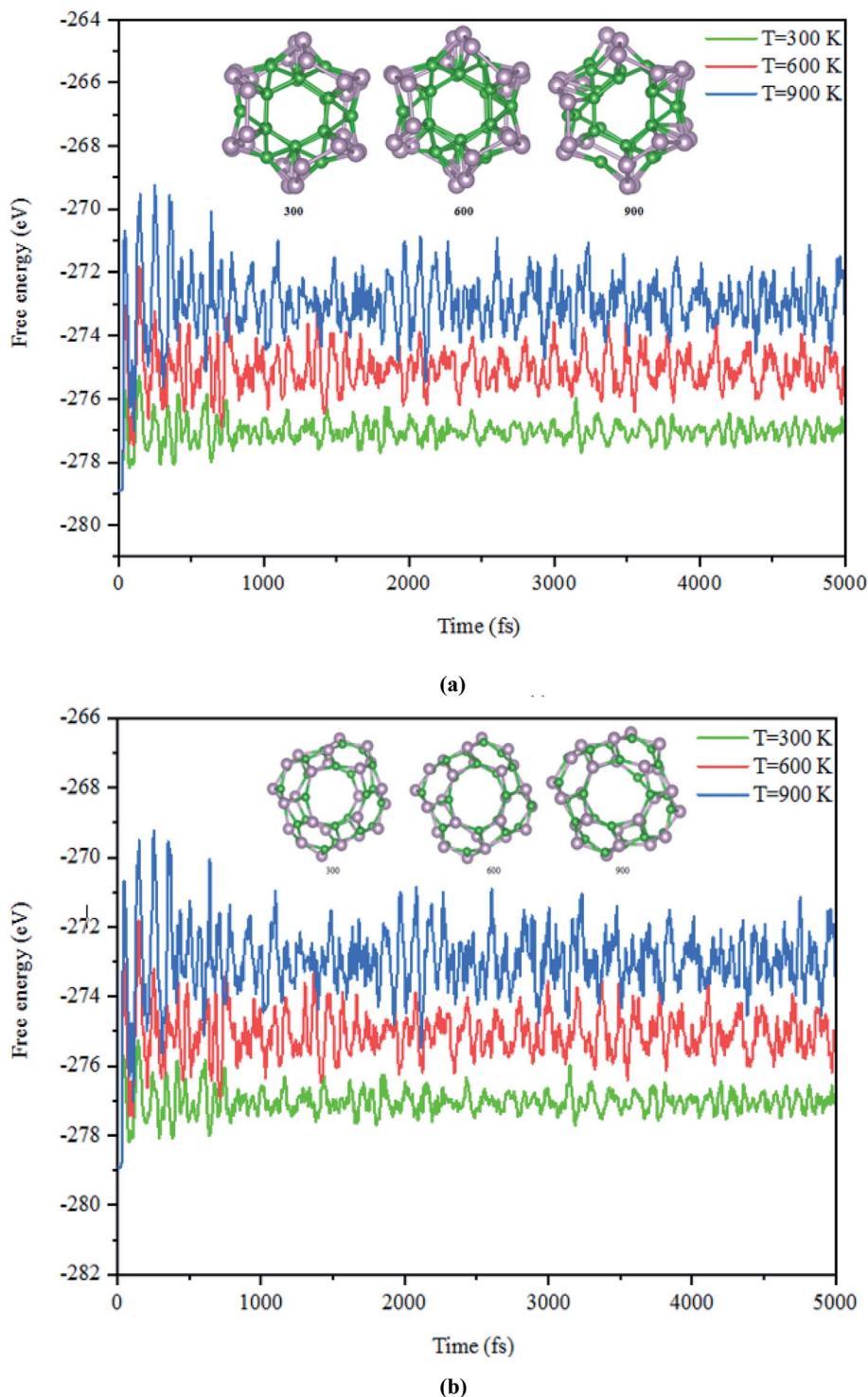


Fig. 4 The snapshots of the most stable structures for a time of 5 ps of (a) α -B₂₄P₂₄ and (b) β -B₂₄P₂₄. The temperature of the AIMD was set to 300, 600, and 900 K.

energy gap implies more kinetic stability and less reactivity. The HSE06 energy gaps of the ground-state structures and the first low-lying isomer of B_nP_n are summarized in Table 2. As represented in Table 2, the H-L energy gaps of the α -B_nP_n and β -B_nP_n clusters are in the range of \sim 0.67–3.2 eV, while the energy gaps in the β -B_nP_n fullerene-like structures are higher than those of

the corresponding α -B_nP_n structures. It is revealed that α -B₁₂P₁₂ and α -B₂₄P₂₄ are semiconductor structures with the HSE06 band gap of 0.67 and 0.62 eV respectively, which is comparable with the band gap of the 2D-BP structure.²⁸ In contrast, β -B₁₂P₁₂ and β -B₂₄P₂₄ fullerene-like structures have large band gaps of 3.2 and 2.98 eV, respectively. The small band gap value suggests



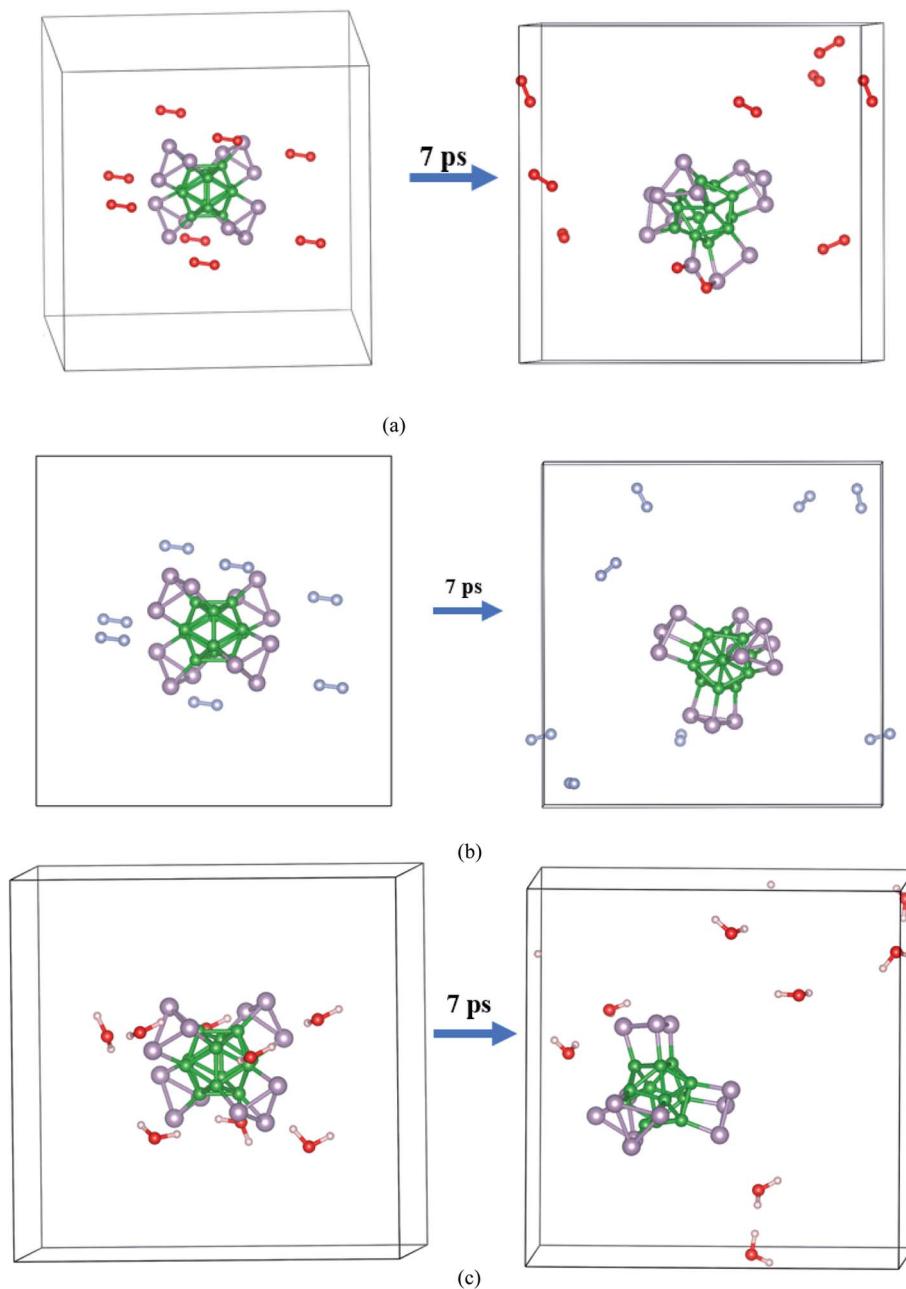


Fig. 5 Initial and final snapshots of the α -B₁₂P₁₂ structure with gaseous phase (a) O₂, (b) N₂, and (c) H₂O after 7 ps AIMD simulations at the temperature of 300 K.

modest chemical stability while the sizeable HOMO–LUMO energy gap is representative of the sufficient chemical stability of the studied clusters. The charge density distribution of the HOMO and LUMO for both the α -B_nP_n and β -B_nP_n structures are presented in Fig. 7. As seen, the HOMO and LUMO orbitals are generally composed of p-orbitals of phosphorus and boron atoms, and they have been distributed over the boron units and B–P bonds. In case of α -B_nP_n, each P atom with sp^3 configuration has one lone pair of electrons in the fourth orbital (bonded with three neighbors of two P and one B atoms).⁸¹

Phosphorus has a higher electronegativity than the boron atom; hence, it is expected that the charge will be transferred

from the B to the P atoms in the BP clusters. Bader charge analysis method is evaluated using the HSE06 functional⁸² and the corresponding values are collected in Table 2. As expected, boron atoms become slightly positively charged with the loss of electron. The amount of total charge transfer from the B atoms to the P atoms in the β -B_nP_n structures is more significant than the corresponding α -B_nP_n structures. Due to the charge transfer between B and P atoms, it is demonstrated that the B_nP_n clusters have polar properties, especially for the β -B_nP_n structures. It can be concluded that charge transfer between the B and P atoms demonstrates that electrostatic interactions have a significant effect on the stability of these types of structures.



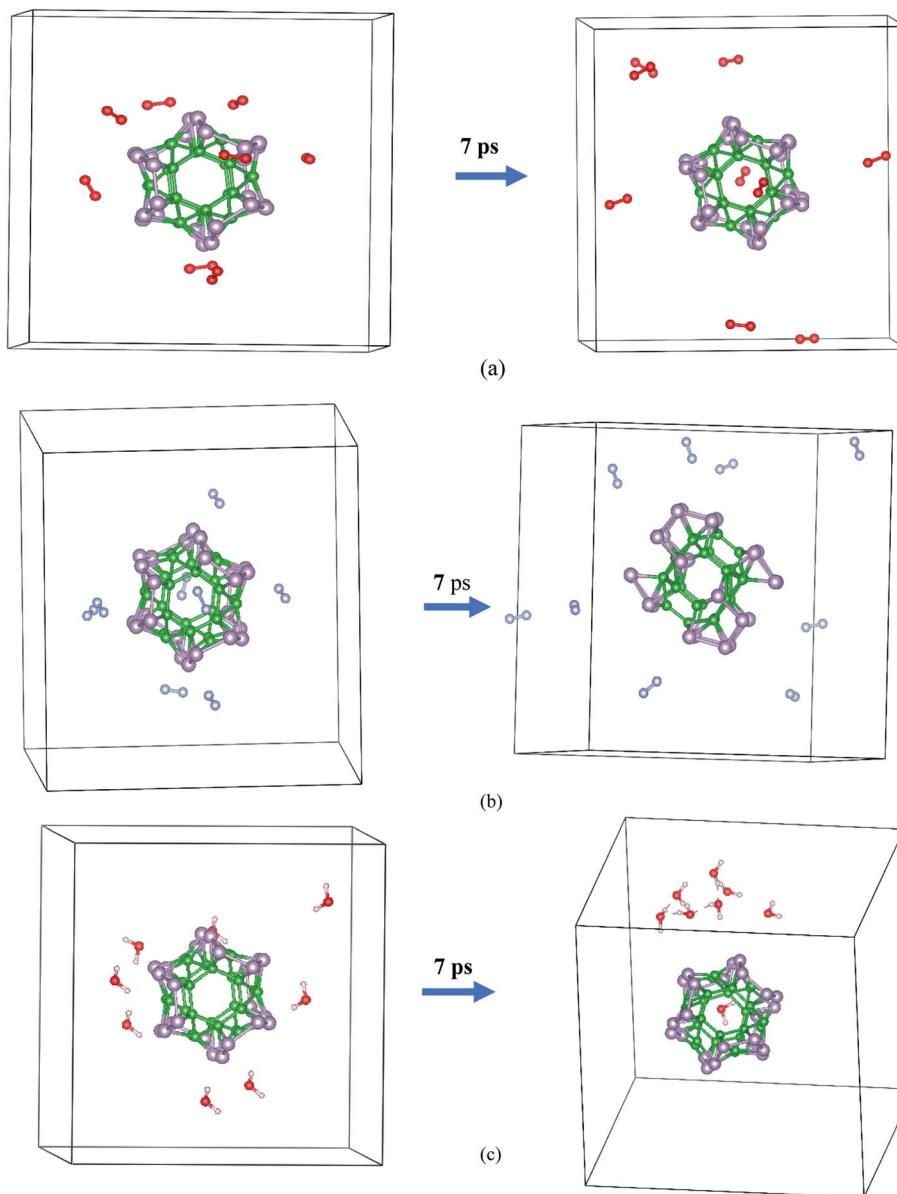


Fig. 6 Initial and final snapshots of the α -B₂₄P₂₄ structure with gaseous phase (a) O₂, (b) N₂, and (c) H₂O after 7 ps AIMD simulations at the temperature of 300 K.

To understand more about the nature of bonds in the B_nP_n structures, the electron localization function (ELF) calculated by VASP is also investigated. ELF can represent electron localization in a molecule and in the solid-state, and its values span from 0 to 1, which illustrates the degree of electron localization. Generally, the considerable value (~ 1) of ELF is consistent with the strong covalent bonds or lone pair of electrons. On the other hand, a small value of ELF points out ionic or metallic bonds, and it shows the low electron density localization. Fig. 8 and S5[†] represent the ELF (isovalue = 0.8 au) of the B_nP_n structures. From these results, it can be realized that electron localization around the P atoms is slightly more than that of the B atoms, which in good agreement with Bader charge analysis. Moreover, the line plots of the ELF values for the B-P bonds indicates the covalent nature of these bonds in the B_nP_n structures (Fig. S6[†]).

The high stability and moderate band gap feature of the investigated B_nP_n clusters motivate us to explore the optical properties of the entitled structures. The optical properties of the B_nP_n clusters have also been studied using the HSE06 functional. To investigate the performance under light, the optical absorption coefficient α was calculated according to the equation below.^{75,83}

$$\alpha(\omega) = \sqrt{2} \omega \left[\sqrt{\varepsilon_1^2(\omega) + \varepsilon_2^2(\omega)} - \varepsilon_1(\omega) \right]^{\frac{1}{2}} \quad (2)$$

where $\varepsilon_1(\omega)$ and $\varepsilon_2(\omega)$ refer to the real and imaginary parts of the complex dielectric functions, respectively. As displayed in Fig. 9, B_nP_n materials exhibit notable absorption in both visible and ultraviolet range with the absorption coefficient larger than 10^5 cm^{-1} , compared to many 2D-materials used as electronic



HOMO

LUMO

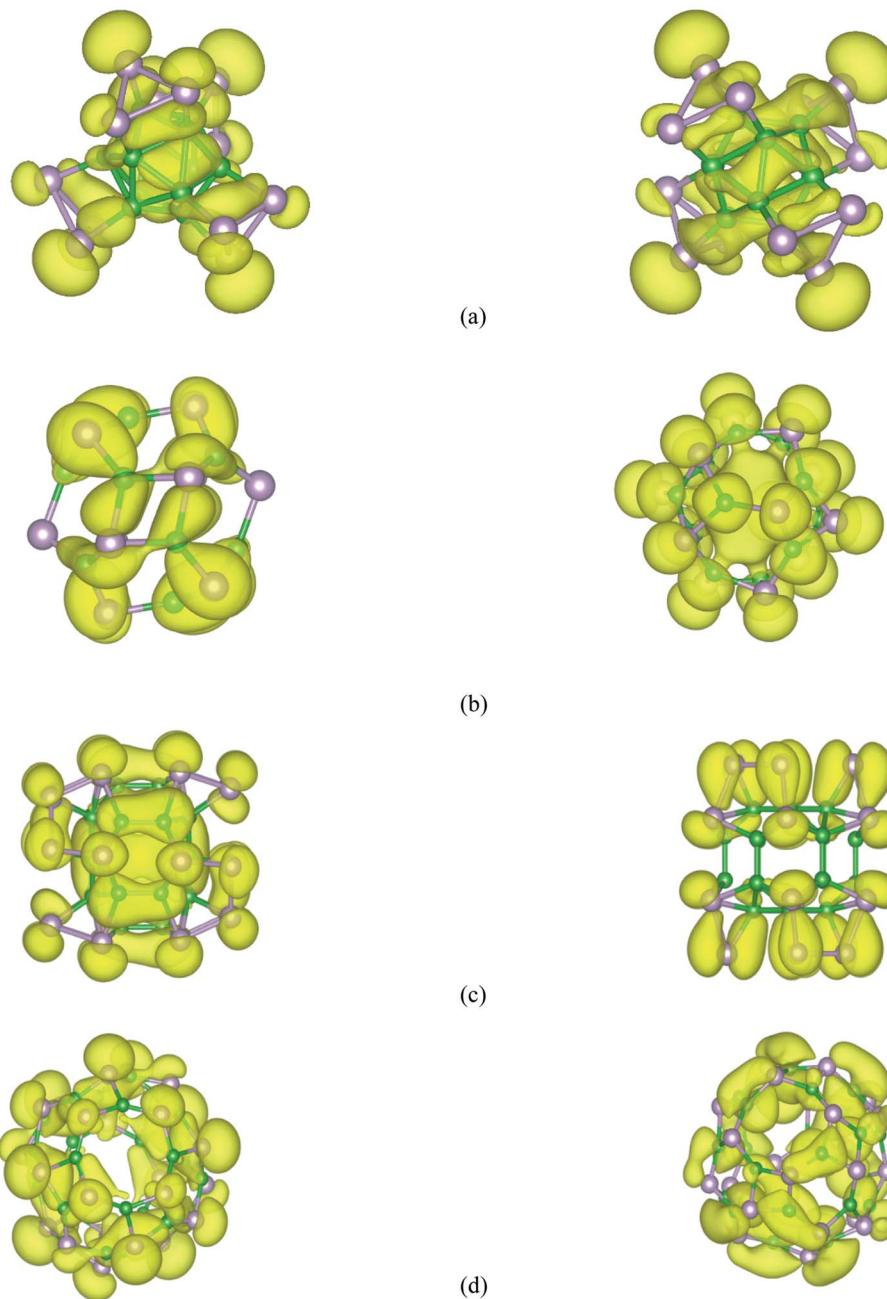


Fig. 7 HSE06-DFT calculated contour plots of the HOMO and LUMOs of (a) α -B₁₂P₁₂, (b) β -B₁₂P₁₂, (c) α -B₂₄P₂₄, and (d) β -B₂₄P₂₄.

and optoelectronic materials.⁸⁴ According to Fig. 9, the optical absorption spectrum of both the structures illustrates a higher degree of absorption in the UV and visible region, which suggests the ability of the α -B_nP_n and β -B_nP_n structures to capture ultraviolet and visible light harvesting. In comparison, α -B_nP_n exhibits stronger optical absorption than those corresponding to the β -B_nP_n structures in the visible region.

Besides, we focused on the potential applications of these compounds for photocatalytic water-splitting. First, the HSE06

position of the valence band maximum (VBM) and the conduction band minimum (CBM) was calculated from the difference between the electrostatic potential at the vacuum region and is shown in Fig. 10. As discussed above, the β -B₁₂P₁₂ and β -B₂₄P₂₄ structures have a band gap of 3.2 and 2.98 eV, respectively, which is located in the visible-light region. The optical absorption of the β -B₁₂P₁₂ and β -B₂₄P₂₄ fullerene-like structures, as shown in Fig. 9, represents that the β -B₁₂P₁₂ and β -B₂₄P₂₄ clusters have expectantly optical absorption in the



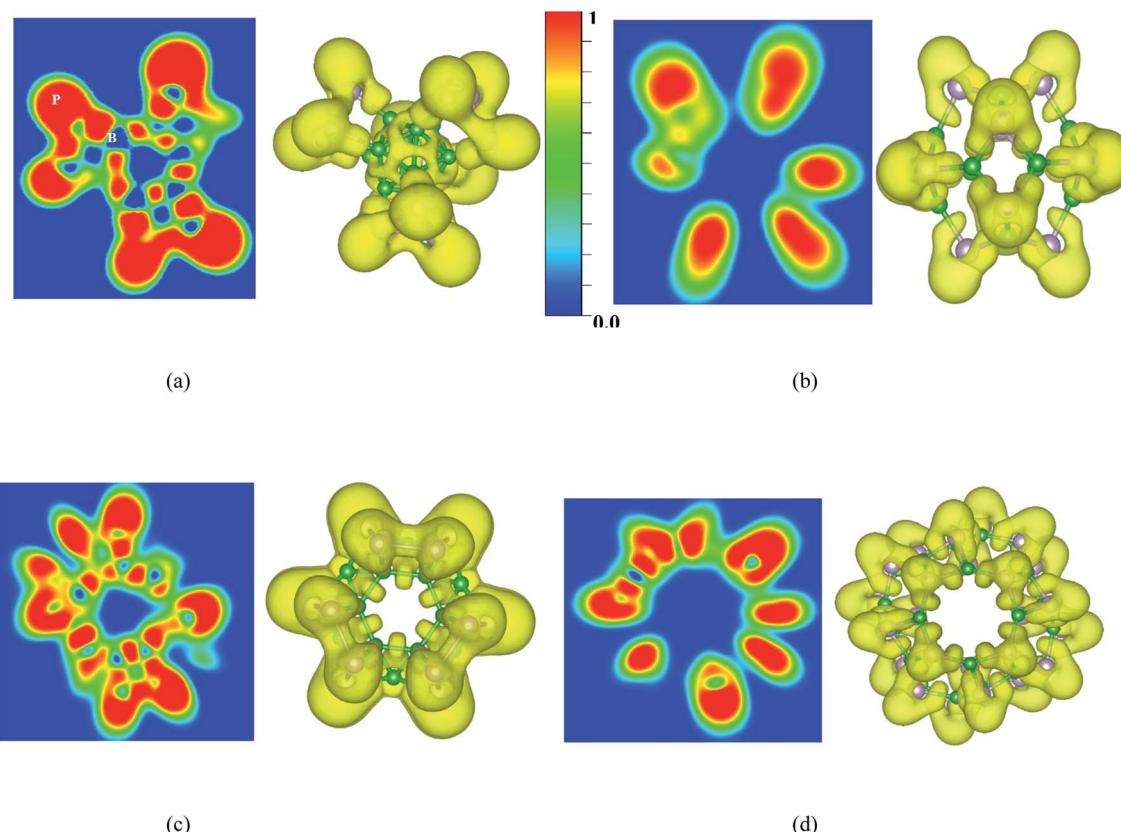


Fig. 8 Contour and 3D plots of the electron localization function (ELF) (isovalue = 0.8 au) for (a) α -B₁₂P₁₂, (b) β -B₁₂P₁₂, (c) α -B₂₄P₂₄, and (d) β -B₂₄P₂₄ calculated by the HSE06 functional.

visible-light region. The optical absorption spectrum of β -B₂₄P₂₄ starts from \sim 550 nm, belonging to 2.25 eV, where the band gap of β -B₂₄P₂₄ is 2.98 eV. On the other hand, the band edge

alignments concerning the oxygen and hydrogen evolution potential levels should be located at proper potentials. Our calculations demonstrate that the VBM and CBMs of the β -

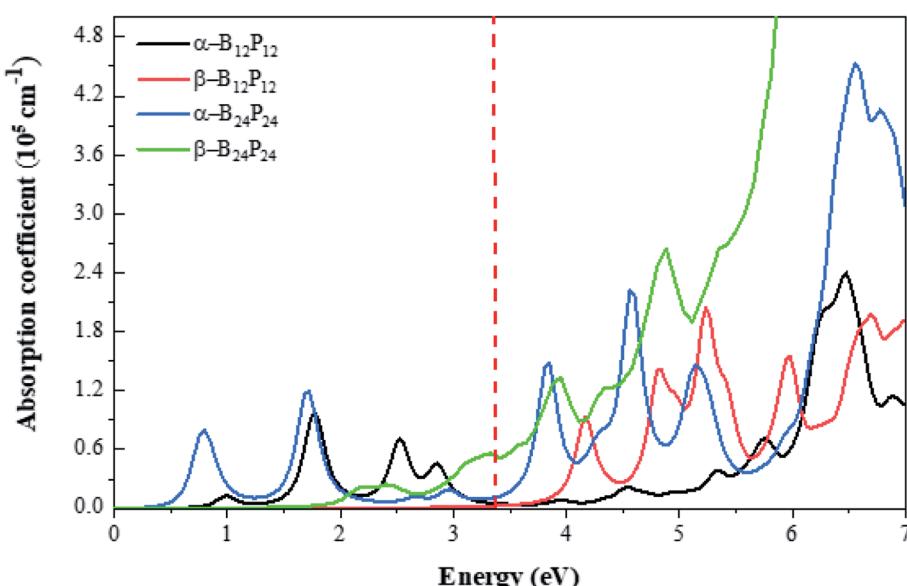


Fig. 9 Optical absorption spectrum of (BP)_n with $n = 12$ and 24 clusters calculated by the HSE06 functional. The energy range corresponding to visible light is indicated by vertical red-dashed lines.



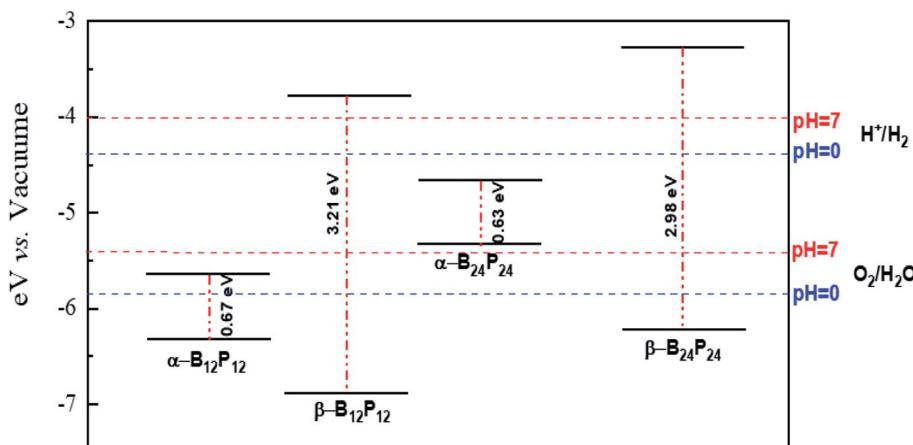


Fig. 10 The local location of VBM and CBM with respect to the vacuum level, calculated with the HSE06 functional. The redox potentials of water splitting at pH = 0 (blue dashed line) and pH = 7 (red dashed line) are shown for comparison.

α -B₁₂P₁₂ and β -B₂₄P₂₄ clusters meet both conditions for photocatalytic water splitting. As seen from Fig. 10, their valence bands lie at more positive potentials than the water oxidation potential (O₂/H₂O potential) and their conduction bands (CBMs) are more negative than the hydrogen reduction potential (H⁺/H₂ potential). These results clearly show that the β -B_nP_n structures have great potential for applications as a visible-light photocatalyst for water splitting. In contrast, the strong absorption coefficient of the α -B₂₄P₂₄ (which can reach a higher order of 5×10^5 cm⁻¹) and α -B₁₂P₁₂ systems is comparable to that of the organic perovskite solar cell. These results reveal that α -B₂₄P₂₄ and α -B₁₂P₁₂ have great potential for applications as optical absorbent materials in solar cells and optoelectronic devices.

3.4. NLO properties

Based on the research conducted to investigate the ability of (XY)_n fullerene-like clusters as NLO materials,^{31,38,85,86} it has motivated us to investigate the second-order NLO properties of both α -B_nP_n and β -B_nP_n structures. Second-order NLO materials that can alter the wavelength of lasers are of considerable interest because of the potential of utilization of such materials in optical switching, optical computing, and photonic technology.^{31,38,85,86} Quartz crystal (α -SiO₂) is a first second-order NLO material, as demonstrated by Franken *et al.* in 1961.^{87,88} In most recent studies, the ability of metal encapsulated (XY)_n nano-cages (X = B, Al, and Y = N, P) as NLO materials has been

considered. They found that the (XY)_n nano-cages have zero dipole moment and zero hyperpolarizability. It should be noted that none of these studies have examined the second-order NLO properties. Herein, for both α -B_nP_n and β -B_nP_n structures, the average polarizability (α), first hyper-polarizabilities (β_0), and second hyperpolarizabilities (γ) were calculated at the CAM-B3LYP/def2-tzvp level of theory using the Gaussian 09 package.⁸⁹ As seen in Table 3, the mean polarizabilities (α) of α -B_nP_n are higher than those of the corresponding β -B_nP_n structures. The maximum value of α is related to the α -B₂₄P₂₄ structure with 965.24 a.u., which is higher than that of the many encapsulated metal-(XY)_n nano-cages.^{31,86} Furthermore, our calculations proved that both α -B_nP_n and β -B_nP_n structures have nearly zero first hyper-polarizabilities (β_0). The second hyperpolarizabilities (γ) of α -B_nP_n and β -B_nP_n are also summarized in Table 3. The second hyper-polarizabilities of all the predicted structures are higher than the experimental values of γ for C₆₀ and C₇₀ fullerenes,^{90,91} and comparable to that of the best NLO materials reported in the literature. On the other hand, α -B₁₂P₁₂ and α -B₂₄P₂₄ have larger γ values than the corresponding β -B_nP_n clusters. The γ value of α -B₂₄P₂₄ is 29 times greater than the second hyper-polarizability value of the β -B₂₄P₂₄ clusters. In conclusion, the strong interactions, effective intermolecular charge transfer, and cluster shape affect the magnitude of the second hyper-polarizabilities of the α -B₁₂P₁₂ and α -B₂₄P₂₄ structures. Furthermore, the α -B₁₂P₁₂ and α -B₂₄P₂₄ clusters show not only high stability but also have large second hyperpolarizability. Hence, they are anticipated to be excellent potential unprecedented candidates for second-order NLO materials.

4. Conclusion

In this work, we explored the new stable structure of B_nP_n ($n = 12, 24$) clusters with a modern method of crystal structure prediction, USPEX conjugated with spin-polarized first-principles calculations. Our prediction demonstrates that the most stable structures of B₁₂P₁₂ and B₂₄P₂₄ are α -B₁₂P₁₂ and α -

Table 3 CAM-B3LYP/def2-tzvp results for the average polarizability (α in a.u.), first hyperpolarizability (β_0 in a.u.), and the average values of the second hyperpolarizability (γ in a.u.) of the (BP)_n clusters

Type	$\langle \alpha \rangle$	β_0	$\langle \gamma \rangle$
α -B ₁₂ P ₁₂	476	10.11	79 172.77
β -B ₁₂ P ₁₂	393.22	0.05	31 780.03
α -B ₂₄ P ₂₄	965.24	385.97	2 581 589
β -B ₂₄ P ₂₄	867.12	0.78	89 540.24



$B_{24}P_{24}$. Based on the relaxed geometries of the α - B_nP_n structures, each phosphorus atom is doped into a boron atom while the B atoms form a B_n unit. In contrast, the first low-lying β - B_nP_n isomers of the $(BP)_n$ clusters are shaped like fullerenes, where each boron atom is bonded to each phosphorus atom to make cage structures. The calculated binding energies for these novel structures are in the range from -4.723 to -4.803 eV per atom, which is much better or comparable to that of other 2D materials and clusters, indicating their excellent stability and possible experimental synthesis. Furthermore, α - B_nP_n structures are more stable than the corresponding β - B_nP_n structures, and the maximum binding energy of -4.803 eV per atom belongs to the α - $B_{24}P_{24}$ structure. Based on our AIMD simulations, it was found that α - B_nP_n structures have relatively high stability in the presence of O_2 , N_2 , and H_2O molecules, in particular, α - $B_{24}P_{24}$ shows superior oxidation resistance. In the case of thermal stability, α - B_nP_n and β - B_nP_n exhibit better thermal stability, where the upper limit temperature that the structures can tolerate is 900 K.

It is revealed that α - $B_{12}P_{12}$ and α - $B_{24}P_{24}$ are semiconductor structures with the HSE06 band gap of 0.67 and 0.62 eV, respectively, which is comparable with the band gap of the 2D-BP structure. In contrast, β - $B_{12}P_{12}$ and β - $B_{24}P_{24}$ fullerene-like structures have large band gaps of 3.2 and 2.98 eV, respectively. The calculated Bader charges illustrate their ionic characters with charge transfers from the B to P atoms. The electronic properties of these novel compounds illustrate a higher degree of absorption in the UV and visible-region with an absorption coefficient larger than 10^5 cm^{-1} , which suggests a wide range of opportunities for advanced optoelectronic applications. The β - B_nP_n phase has suitable band alignments in the visible-light excitation region, which will produce enhanced photocatalytic water splitting. On the other hand, α - B_nP_n structures with high absorption coefficient exhibit large second hyperpolarizability, which are expected to have excellent potential as second-order NLO materials.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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